

## Schottky Rectifier, 100Ax2 / 100V

### FEATURES

- 175°C  $T_J$  operation
- Center tap module
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead (Pb)-free
- Designed and qualified for industrial level

### DESCRIPTION

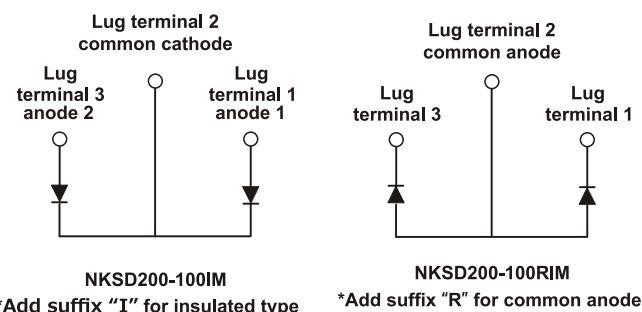
The NKSD200-100IM Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175°C junction temperature.

### TYPICAL APPLICATIONS

- High current switching power supplies
- Plating power supplies
- UPS system
- Converters
- Freewheeling
- Welder
- Reverse battery protection.



TO-244M (insulated)

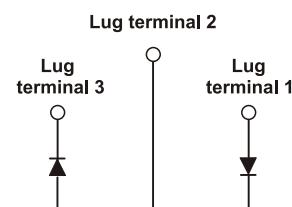


NKSD200-100IM

\*Add suffix "I" for insulated type

NKSD200-100RIM

\*Add suffix "R" for common anode



NKSD200-100AIM

\*Add suffix "A" for half-bridge

### PRODUCT SUMMARY

$I_{F(AV)}$	200A
$V_R$	100V

### MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNIT
$I_{F(AV)}$	Rectangular waveform	200	A
$V_{RRM}$		100	V
$I_{FSM}$	$t_p = 5 \mu s$ sine	12800	A
$V_F$	100 Apk, $T_J = 125^\circ C$ (per leg)	0.70	V
$T_J$	Range	-55 to 175	°C

### VOLTAGE RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Maximum DC reverse voltage	$V_R$	100	V
Maximum working peak reverse voltage	$V_{RWM}$		

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNIT	
Maximum average forward current See fig.5	$I_{F(AV)}$	per leg per device			50% duty cycle at $T_J = 135^\circ\text{C}$ , rectangular waveform	A	
					100 200		
Maximum peak one cycle non-repetitive surge current per leg See fig.7	$I_{FSM}$	5 $\mu\text{s}$ sine or 3 $\mu\text{s}$ rect. pulse		Following any rated load condition and with rated $V_{RRM}$ applied	12800 1700		
		10 ms sine or 6 ms rect. pulse					
Non- repetitive avalanche energy per leg	$E_{AS}$	$T_J = 25^\circ\text{C}$ , $I_{AS} = 13\text{A}$ , $L = 0.2\text{mH}$			15	$\text{mJ}$	
Repetitive avalanche current per leg	$I_{AR}$	Current decaying linearly to zero in 1 $\mu\text{s}$ Frequency limited by $T_J$ maximum $V_A = 1.5 \times V_R$ typical			1	A	

ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNIT		
Maximum forward voltage drop per leg See fig.1	$V_{FM}^{(1)}$	100A	$T_J = 25^\circ\text{C}$		0.85	V		
		200A			1.05			
		100A	$T_J = 125^\circ\text{C}$		0.70			
		200A			0.85			
Maximum reverse leakage current per leg See fig.2	$I_{RM}^{(1)}$	$T_J = 25^\circ\text{C}$	$V_R = \text{Rated } V_R$		50	$\mu\text{A}$		
		$T_J = 125^\circ\text{C}$			20	$\text{mA}$		
Maximum junction capacitance per leg	$C_T$	$V_R = 5 \text{ V}_{\text{DC}}$ (test signal range 100 kHz to 1 MHz) $25^\circ\text{C}$			2650	$\text{pF}$		
Typical series inductance per leg	$L_s$	From top of terminal hole to mounting plane			7	$\text{nH}$		
Maximum voltage rate of change	$dV/dt$	Rated $V_R$			10000	$\text{V}/\mu\text{s}$		
Maximum RMS insulation voltage	$V_{INS}$				1000 (1min)	V		

Note

(1) Pulse width < 300  $\mu\text{s}$ , duty cycle < 2%

THERMAL-MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Maximum junction and storage temperature range	$T_J, T_{Stg}$	-55	-	175	$^\circ\text{C}$	
Thermal resistance, junction to case per leg	$R_{thJC}$	-	-	0.50	$^\circ\text{C}/\text{W}$	
Thermal resistance, junction to case per module	$R_{thJC}$	-	-	0.25		
Thermal resistance, case to heatsink	$R_{thCS}$	-	0.10	-		
Weight		-	95 (3.35)	-	g(oz.)	
Mounting torque, M6		30 (3.4)	-	40 (4.6)	$\text{lbf} \cdot \text{in}$ ( $\text{N} \cdot \text{m}$ )	
Terminal torque, M6		30 (3.4)	-	40 (4.6)		
vertical pull		-	-	80	$\text{lbf} \cdot \text{in}$	
2" lever pull		-	-	35		
Case style	JEDEC	TO-244AA compatible				

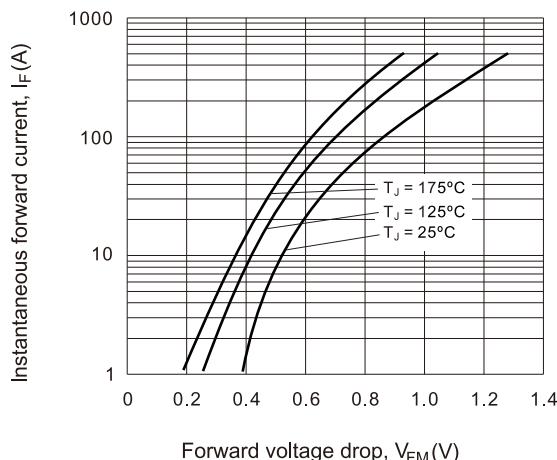
### Ordering Information Table

Device code

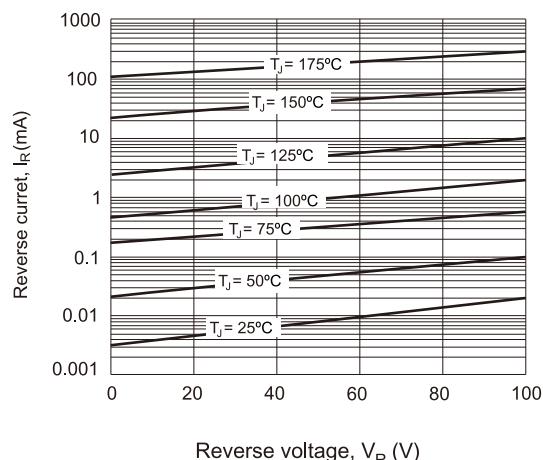
<b>N</b>	<b>K</b>	<b>S</b>	<b>D</b>	<b>200</b>	-	<b>100</b>	<b>R</b>	<b>I</b>	<b>M</b>
(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)		

- [1] - NPS power module
- [2] - S for Schottky Barrier Diode
- [3] - D for Dual Diodes, TO-244 Package
- [4] - Maximum average forward current, A
- [5] - Voltage rating (100 = 100V)
- [6] - None for common cathode configuration  
"R" for common anode configuration,"A" for half-bridge configuration
- [7] - "I" for insulated type
- [8] - "M" for TO-224M Package ( Molding type TO-244 )

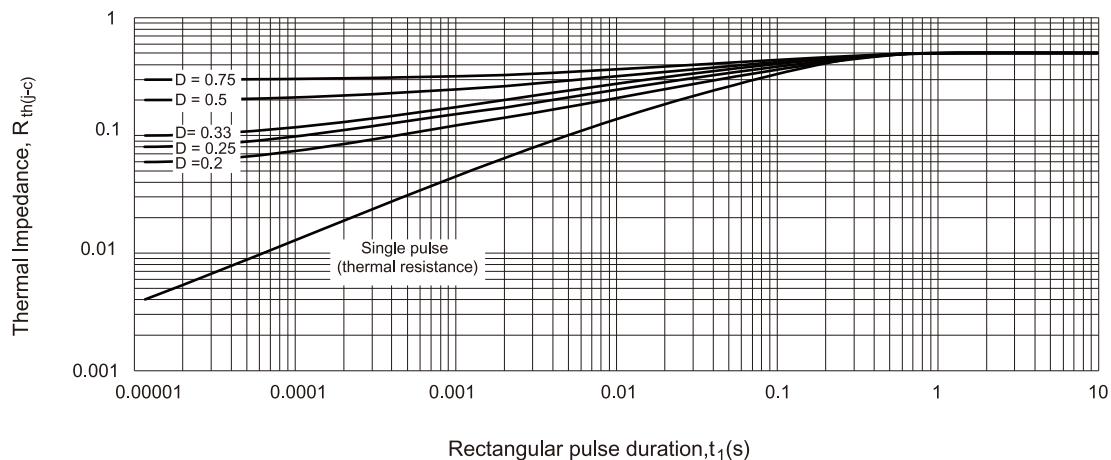
**Fig.1 Maximum forward voltage drop characteristics (Per Leg)**



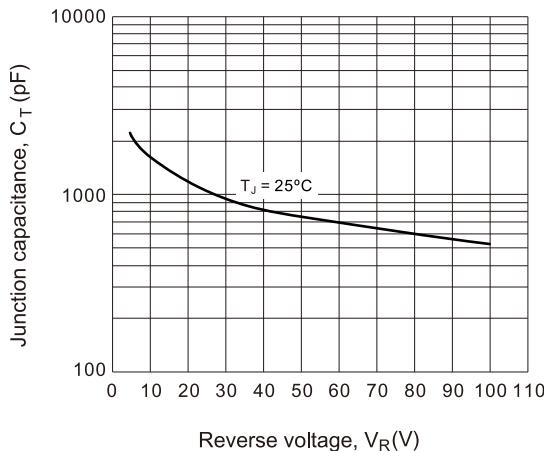
**Fig.2 Typical values of reverse current vs. Reverse voltage (Per Leg)**



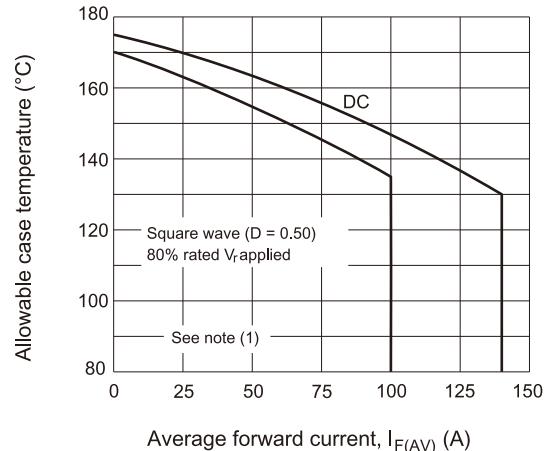
**Fig.3 Maximum thermal impedance  $R_{th(j-c)}$  characteristics (Per Leg)**



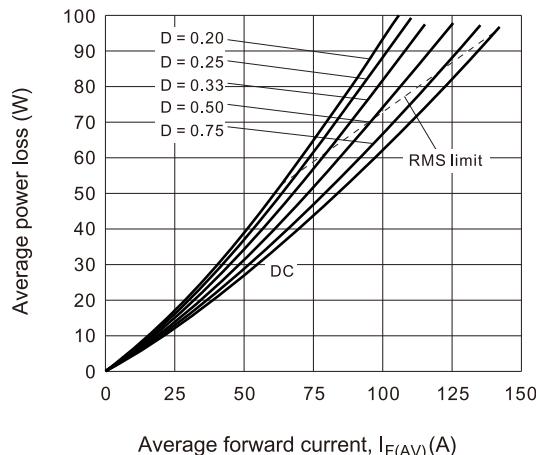
**Fig.4 Typical junction capacitance vs. Reverse voltage (Per Leg )**



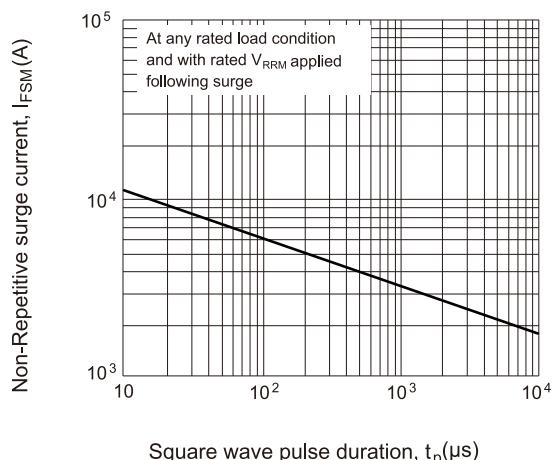
**Fig.5 Maximum allowable case temperature vs. Average forward current (Per Leg)**



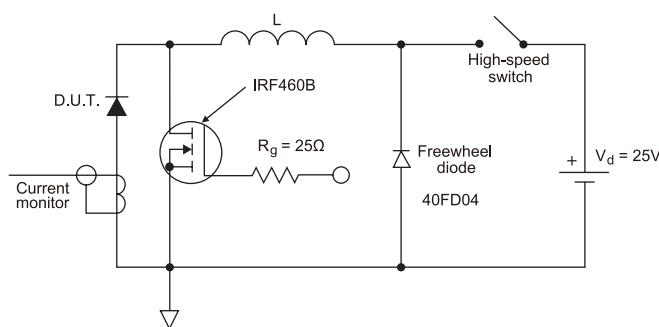
**Fig.6 Forward power loss characteristics (Per Leg)**



**Fig.7 Maximum non-repetitive surge current (Per Leg)**

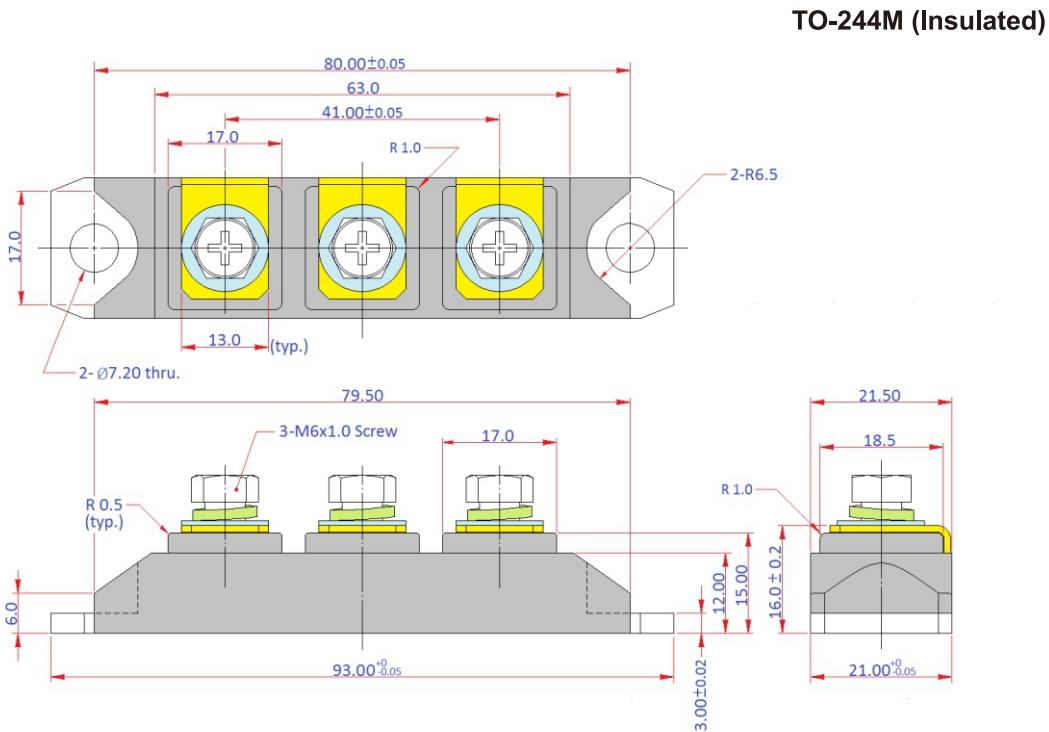


**Fig.8 Unclamped Inductive test circuit**



Note

- (1) Formula used:  $T_C = T_J - (P_d + P_{d\text{REV}}) \times R_{thJC}$ ;
- $P_d = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D)$  (see fig.6)
- $P_{d\text{REV}} = \text{Inverse power loss} = V_{R1} \times I_R(1-D)$ ;  $I_R$  at  $V_{R1} = 80\%$  rated  $V_R$



All dimensions in millimeters